

# GS1Z

## Features

- For surface mounted application
- Low forward voltage drop
- High current capability
- High reliability
- Classification Rating 94V-0

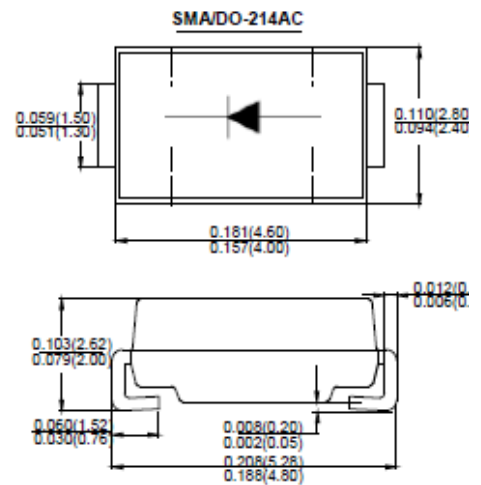
## Mechanical Data

**Case:** molded plastic SMA/DO-214AC

**Polarity:** Color band denotes cathode end

**Mounting position:** Any

**Terminals:** Solder plated, solderable per MIL-STD-750,  
Method 2026 guaranteed



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load

For capacitive load, derate current by 20%

Type Number	Symbol	GS1Z	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	2000	V
Maximum RMS Voltage	$V_{RMS}$	1400	V
Maximum DC Blocking Voltage	$V_{DC}$	2000	V
Maximum average forward rectified current @TL = 110°C	$I_{(AV)}$	1.0	A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	$I_{FSM}$	30	A
Maximum Instantaneous Forward Voltage @ 1.0A	$V_F$	1.15	V
Maximum DC Reverse Current @ TA=25°C at Rated DC Blocking Voltage @ TA=100°C	$I_R$	5.0 50.0	uA
Maximum Reverse Recovery Time (Note 1)	$T_{rr}$	2500	ns
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150	°C

Note:

1. Reverse Recovery Test Conditions:  $I_F=0.5A, I_R=1.0A, I_{RR}=0.25A$

## Characteristic Curves

Fig. 1 - Forward Current Derating Curve

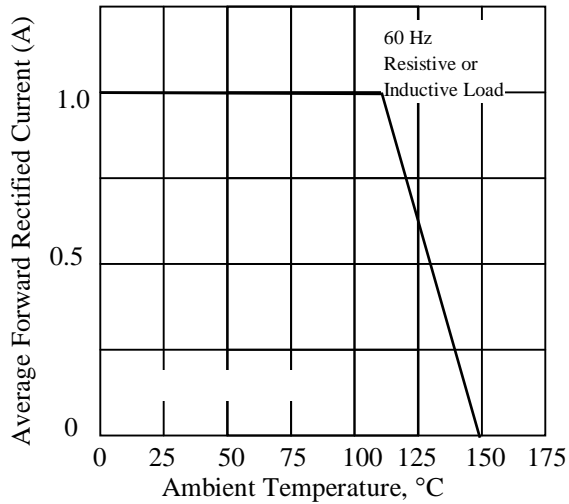


Fig. 2 - Maximum Non-repetitive Peak Forward Surge Current

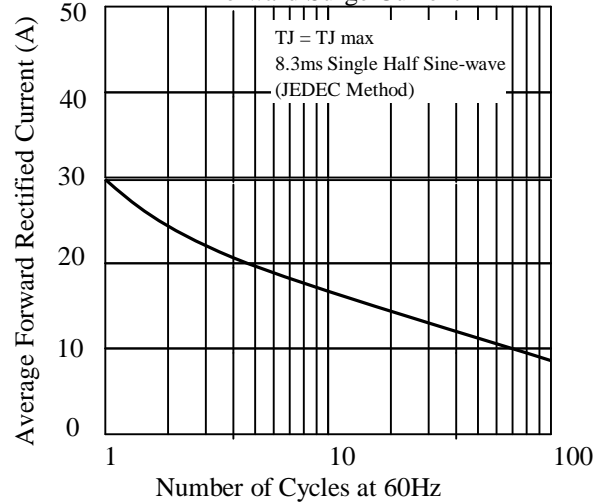


Fig. 3 - Typical Instantaneous Forward Characteristics

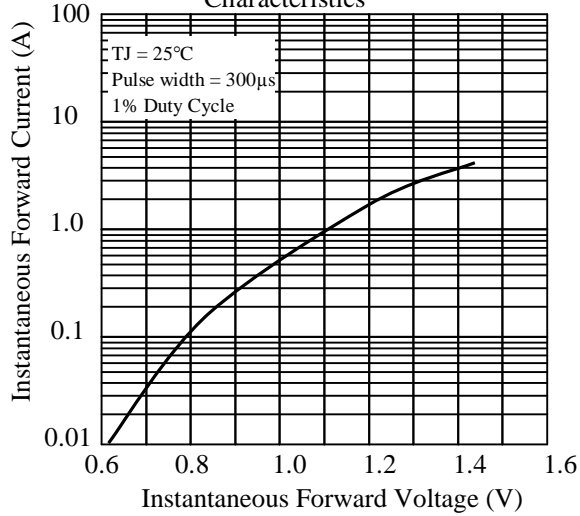


Fig. 4 - Typical Reverse Characteristics

